	3.3-V ABT O		SN54LVTH574, SN74LVTH574 GGERED D-TYPE FLIP-FLOPS WITH 3-STATE OUTPUTS 35688G - MAY 1997 - REVISED SEPTEMBER 2003				
<ul> <li>Support Mixed-Mode Signal O Input and Output Voltages Wit</li> <li>Support Unregulated Battery O Down to 2.7 V</li> <li>Typical V<sub>OLP</sub> (Output Ground I &lt;0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C</li> <li>I<sub>off</sub> and Power-Up 3-State Supplication</li> </ul>	h 3.3-V V <sub>CC</sub> ) Operation Bounce)	<ul> <li>Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors</li> <li>Latch-Up Performance Exceeds 500 mA Per JESD 17</li> <li>ESD Protection Exceeds JESD 22         <ul> <li>2000-V Human-Body Model (A114-A)</li> <li>200-V Machine Model (A115-A)</li> </ul> </li> </ul>					
$\begin{array}{c} \text{SN54LVTH574} \dots \text{J OR W PACKAGE} \\ \text{SN74LVTH574} \dots \text{DB, DW, NS,} \\ \text{OR PW PACKAGE} \\ \text{(TOP VIEW)} \\ \hline \\ $		20 20 20 19 18 2Q 17 3Q 16 4Q 15 5Q 14 6Q 13 7Q 8Q 11 Y O	SN54LVTH574FK PACKAGE (TOP VIEW) $\begin{array}{c} 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 $				

## description/ordering information

These octal flip-flops are designed specifically for low-voltage (3.3-V) V<sub>CC</sub> operation, but with the capability to provide a TTL interface to a 5-V system environment.

T <sub>A</sub>	PACKAGE	t	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RGY	Tape and reel	SN74LVTH574RGYR	LXH574
		Tube	SN74LVTH574DW	
	SOIC – DW	Tape and reel	SN74LVTH574DWR	LVTH574
	SOP – NS	Tape and reel	SN74LVTH574NSR	LVTH574
–40°C to 85°C	SSOP – DB	Tape and reel	SN74LVTH574DBR	LXH574
	TOOOD DW	Tube	SN74LVTH574PW	
	TSSOP – PW	Tape and reel	SN74LVTH574PWR	LXH574
	VFBGA – GQN	Transformed	SN74LVTH574GQNR	
	VFBGA – ZQN (Pb-free)	Tape and reel	SN74LVTH574ZQNR	LXH574
	CDIP – J	Tube	SNJ54LVTH574J	SNJ54LVTH574J
–55°C to 125°C	CFP – W	Tube	SNJ54LVTH574W	SNJ54LVTH574W
	LCCC – FK	Tube	SNJ54LVTH574FK	SNJ54LVTH574FK

### **ORDERING INFORMATION**

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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## description/ordering information (continued)

The eight flip-flops of the 'LVTH574 devices are edge-triggered D-type flip-flops. On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels set up at the data (D) inputs.

A buffered output-enable (OE) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

OE does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, OE should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

These devices are fully specified for hot-insertion applications using Ioff and power-up 3-state. The Ioff circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

## SN74LVTH574 ... GQN OR ZQN PACKAGE



## terminal assignments

	1	2	3	4
A	1D	ŌĒ	V <sub>CC</sub>	1Q
в	3D	3Q	2D	2Q
С	5D	4D	5Q	4Q
D	7D	7Q	6D	6Q
Е	GND	8D	CLK	8Q

#### **FUNCTION TABLE** (each flip-flop)

	INPUTS	OUTPUT	
ŌE	CLK	D	Q
L	$\uparrow$	Н	Н
L	$\uparrow$	L	L
L	H or L	Х	Q <sub>0</sub>
Н	Х	Х	Z



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## logic diagram (positive logic)



To Seven Other Channels

Pin numbers shown are for the DB, DW, FK, J, NS, PW, RGY, and W packages.

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, V <sub>CC</sub>	-0.5 V to 4.6 V -0.5 V to 7 V
Voltage range applied to any output in the high-impedance or power-off state, V <sub>O</sub> (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state, V <sub>O</sub> (see Note 1)	
Current into any output in the low state, Io: SN54LVTH574	
SN74LVTH574	128 mA
Current into any output in the high state, I <sub>O</sub> (see Note 2): SN54LVTH574	48 mA
SN74LVTH574	64 mA
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	
Package thermal impedance, $\theta_{JA}$ (see Note 3): DB package	
(see Note 3): DW package	58°C/W
(see Note 3): GQN/ZQN package	
(see Note 3): NS package	60°C/W
(see Note 3): PW package	83°C/W
(see Note 4): RGY package	37°C/W
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. This current flows only when the output is in the high state and  $V_O > V_{CC}$ .

3. The package thermal impedance is calculated in accordance with JESD 51-7.

4. The package thermal impedance is calculated in accordance with JESD 51-5.



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## recommended operating conditions (see Note 5)

			SN54LV	TH574	SN74LV	TH574	
			MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	2.7	3.6	2.7	3.6	V	
V <sub>IH</sub>	High-level input voltage		2		2		V
V <sub>IL</sub>	Low-level input voltage		0.8		0.8	V	
VI	Input voltage			5.5		5.5	V
I <sub>OH</sub>	High-level output current			-24		-32	mA
I <sub>OL</sub>	Low-level output current			48		64	mA
$\Delta t / \Delta v$	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
$\Delta t / \Delta V_{CC}$	Power-up ramp rate		200		200		μs/V
T <sub>A</sub>	Operating free-air temperature	-55	125	-40	85	°C	

NOTE 5: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

				SN	54LVTH	574	SN7	4LVTH5	574		
PA	RAMETER	TESTC	ONDITIONS	MIN	TYP <sup>†</sup>	MAX	MIN	TYP <sup>†</sup>	MAX	UNIT	
V <sub>IK</sub>		V <sub>CC</sub> = 2.7 V,	I <sub>I</sub> = -18 mA			-1.2			-1.2	V	
		$V_{CC} = 2.7 V \text{ to } 3.6 V,$	I <sub>OH</sub> = −100 μA	V <sub>CC</sub> -0.2	V <sub>CC</sub> -0.2		V <sub>CC</sub> -0.2	2			
.,		V <sub>CC</sub> = 2.7 V,	I <sub>OH</sub> = -8 mA	2.4			2.4			.,	
V <sub>OH</sub>			I <sub>OH</sub> = -24 mA	2						V	
		$V_{CC} = 3 V$	I <sub>OH</sub> = -32 mA				2				
			I <sub>OL</sub> = 100 μA			0.2			0.2		
		V <sub>CC</sub> = 2.7 V	I <sub>OL</sub> = 24 mA			0.5			0.5		
			I <sub>OL</sub> = 16 mA			0.4			0.4	v	
V <sub>OL</sub>		V 2V	I <sub>OL</sub> = 32 mA			0.5			0.5	v	
		$V_{CC} = 3 V$	I <sub>OL</sub> = 48 mA			0.55					
			I <sub>OL</sub> = 64 mA					0.55			
	Control innuto	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V <sub>I</sub> = 5.5 V			10			10		
	Control inputs	V <sub>CC</sub> = 3.6 V,	$V_I = V_{CC}$ or GND		±1				±1		
I	Data inputs	V <sub>CC</sub> = 3.6 V	$V_{I} = V_{CC}$			1			1	μA	
		VCC = 3.0 V	V <sub>I</sub> = 0			-5			-5		
I <sub>off</sub>		$V_{CC} = 0,$	$V_{I}$ or $V_{O}$ = 0 to 4.5 V						±100	μA	
		V <sub>CC</sub> = 3 V	V <sub>I</sub> = 0.8 V	75			75				
l <sub>i(hold)</sub>	Data inputs	$v_{CC} = 3 v$	V <sub>I</sub> = 2 V	-75			-75			μA	
		$V_{CC} = 3.6 V^{\ddagger},$	V <sub>I</sub> = 0 to 3.6 V						±500		
I <sub>OZH</sub>		V <sub>CC</sub> = 3.6 V,	V <sub>O</sub> = 3 V			5			5	μA	
I <sub>OZL</sub>		V <sub>CC</sub> = 3.6 V,	V <sub>O</sub> = 0.5 V			-5			-5	μA	
I <sub>OZPU</sub>		$\frac{V_{CC}}{OE} = 0 \text{ to } 1.5 \text{ V}, \text{ V}_{O} = 0$	0.5 V to 3 V,			±100*			±100	μA	
I <sub>OZPD</sub>		$\frac{V_{CC}}{OE} = 1.5 \text{ V to 0, } V_{O} = $	0.5 V to 3 V,			±100*			±100	μA	
		V <sub>CC</sub> = 3.6 V,	Outputs high			0.19			0.19		
I <sub>CC</sub>		$l_0 = 0,$	Outputs low			5			5	mA	
		$V_{I} = V_{CC}$ or GND	Outputs disabled		0.19		0.19		l		
$\Delta I_{CC}$ §		$V_{CC} = 3 V$ to 3.6 V, One Other inputs at $V_{CC}$ or				0.2			0.2	mA	
Ci		V <sub>I</sub> = 3 V or 0			3			3		pF	
Co		V <sub>O</sub> = 3 V or 0			7			7		pF	

\* On products compliant to MIL-PRF-38535, this parameter is not production tested.

<sup>†</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C.

<sup>‡</sup> This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

§ This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V<sub>CC</sub> or GND.



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# timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			SN54LV	/TH574		SN74LVTH574				
		V <sub>CC</sub> = ± 0.3	V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 2.7 V	
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>clock</sub>	Clock frequency		150		150		150		150	MHz
tw	Pulse duration, CLK high or low	3.3		3.3		3.3		3.3		ns
t <sub>su</sub>	Setup time, data before CLK↑	2		2.4		2		2.4		ns
t <sub>h</sub>	Hold time, data after $CLK^\uparrow$	0.9		0.9		0.3		0		ns

# switching characteristics over recommended free-air temperature, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

				SN54LVTH574				SN74LVTH574					
PARAMETER	FROM (INPUT)	-	TO (OUTPUT)	V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V			V <sub>CC</sub> = 2.7 V		UNIT
			MIN	MAX	MIN	MAX	MIN	TYP <sup>†</sup>	MAX	MIN	MAX		
f <sub>max</sub>			150		150		150			150		MHz	
t <sub>PLH</sub>	CLK	0	1.7	4.9		5.9	1.8	3	4.5		5.3	20	
t <sub>PHL</sub>	ULK	Q	1.7	4.9		5.5	1.8	3	4.5		5.3	5.3 ns	
t <sub>PZH</sub>	ŌĒ	0	1.4	5.1		6.5	1.5	3.2	4.8		5.9		
t <sub>PZL</sub>	OE	Q	1.4	5.1		6.1	1.5	3.5	4.8		5.9	ns	
t <sub>PHZ</sub>	ŌĒ	0	1	5.9		6.4	2	3.5	4.8		5.1		
t <sub>PLZ</sub>	OE	Q	0.8	4.8		5.3	2	3.2	4.4		4.4	ns	

 $^{\dagger}$  All typical values are at V\_{CC} = 3.3 V, T\_{A} = 25°C.



# SN54LVTH574, SN74LVTH574 3.3-V ABT OCTAL EDGE-TRIGGERED D-TYPE FLIP-FLOPS

WITH 3-STATE OUTPUTS SCBS688G – MAY 1997 – REVISED SEPTEMBER 2003



## PARAMETER MEASUREMENT INFORMATION

NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

## Figure 1. Load Circuit and Voltage Waveforms





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## **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
5962-9583201Q2A	ACTIVE	LCCC	FK	20	1	TBD	Call TI	Call TI	
5962-9583201QRA	ACTIVE	CDIP	J	20	1	TBD	Call TI	Call TI	
5962-9583201QSA	ACTIVE	CFP	W	20	1	TBD	Call TI	Call TI	
5962-9583201VRA	ACTIVE	CDIP	J	20	20	TBD	A42	N / A for Pkg Type	
5962-9583201VSA	ACTIVE	CFP	W	20	25	TBD	Call TI	N / A for Pkg Type	
SN74LVTH574DB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574DBE4	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574DBG4	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574DBLE	OBSOLETE	SSOP	DB	20		TBD	Call TI	Call TI	
SN74LVTH574DBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574DBRE4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574DBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574NSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	



23-Mar-2012

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
SN74LVTH574NSRE4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574NSRG4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574PW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574PWE4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574PWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574PWLE	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	
SN74LVTH574PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574PWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVTH574RGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SN74LVTH574RGYRG4	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SNJ54LVTH574FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	
SNJ54LVTH574J	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	
SNJ54LVTH574W	ACTIVE	CFP	W	20	1	TBD	Call TI	N / A for Pkg Type	

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.



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Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above. Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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#### OTHER QUALIFIED VERSIONS OF SN54LVTH574, SN54LVTH574-SP, SN74LVTH574 :

Catalog: SN74LVTH574, SN54LVTH574

- Enhanced Product: SN74LVTH574-EP, SN74LVTH574-EP
- Military: SN54LVTH574
- Space: SN54LVTH574-SP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

# PACKAGE MATERIALS INFORMATION

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# TAPE AND REEL INFORMATION

## REEL DIMENSIONS

TEXAS INSTRUMENTS





TAPE AND REEL INFORMATION

#### TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

*All dimensions are nominal												
Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH574DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVTH574DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN74LVTH574NSR	SO	NS	20	2000	330.0	24.4	8.2	13.0	2.5	12.0	24.0	Q1
SN74LVTH574PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74LVTH574RGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

14-Jul-2012



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH574DBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74LVTH574DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVTH574NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LVTH574PWR	TSSOP	PW	20	2000	367.0	367.0	38.0
SN74LVTH574RGYR	VQFN	RGY	20	3000	367.0	367.0	35.0

J (R-GDIP-T\*\*) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- NOTES: A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. This package can be hermetically sealed with a ceramic lid using glass frit.
  - D. Index point is provided on cap for terminal identification only.
  - E. Falls within Mil-Std 1835 GDFP2-F20



LEADLESS CERAMIC CHIP CARRIER

FK (S-CQCC-N\*\*) 28 TERMINAL SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AC.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.  $\beta$ . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



# LAND PATTERN DATA



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# **MECHANICAL DATA**



- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



# RGY (R-PVQFN-N20)

# PLASTIC QUAD FLATPACK NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



#### NOTE: All linear dimensions are in millimeters





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.

D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>.

- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



# MECHANICAL DATA

## PLASTIC SMALL-OUTLINE PACKAGE

### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# **MECHANICAL DATA**

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

# DB (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



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